

isc Silicon NPN Darlington Power Transistor

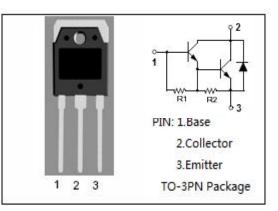
2SD1210

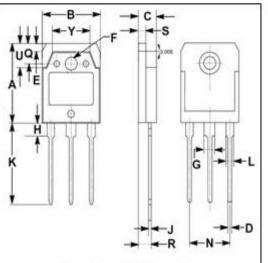
DESCRIPTION

- High DC Current Gain
 - : h_{FE}= 1000(Min.)@ I_C= 10A
- Collector-Emitter Sustaining Voltage-: V_{CEO(SUS)} = 100V(Min)
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

APPLICATIONS

• Designed for audio frequency power amplifier and low speed high current switching industrial use.





	mm			
DIM	MIN	MAX		
Α	19.60	20.30		
В	15.50	15.70		
С	4.70	4.90		
D	0.90	1.10		
Ε	1.90	2.10		
F	3.40	3.60		
G	2.90	3.20		
Н	3.20	3.40		
J	0.595	0.605		
Κ	19.80	20.70		
L	1.90	2.20		
Ν	10.89	10.91		
Q	4.90	5.10		
R	3.35	3.45		
S	1.995	2.100		
U	5.90	6.20		
Y	9.90	10.10		

ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

isc website: www.iscsemi.com

SYMBOL	PARAMETER	VALUE	UNIT	
V _{CBO}	Collector-Base Voltage	150	V	
V _{CEO}	Collector-Emitter Voltage	100	V	
V _{EBO}	Emitter-Base Voltage 8		V	
lc	Collector Current-Continuous 10		А	
I _{CM}	Collector Current-Peak	20	А	
Ів	Base Current- Continuous	1	А	
Pc	Collector Power Dissipation @T₂=25℃	3	W	
	Collector Power Dissipation @Tc=25°C	80		
Tj	Junction Temperature	150	°C	
T _{stg}	Storage Temperature Range	-55~150	°C	

¹ isc & iscsemi is registered trademark



isc Silicon NPN Darlington Power Transistor

2SD1210

ELECTRICAL CHARACTERISTICS

$T_c=25^{\circ}C$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	МАХ	UNIT
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C = 10A, I _B = 25mA			1.5	V
V _{BE(sat)}	Base-Emitter Saturation Voltage	I _C = 10A, I _B = 25mA			2.0	V
Ісво	Collector Cutoff current	V _{CB} = 100V, I _E = 0			10	μA
I _{EBO}	Emitter Cutoff Current	V _{EB} = 8V; I _C = 0			5	mA
h _{FE}	DC Current Gain	I _C = 10A; V _{CE} = 2V	1000			

Switching Times

ton	Turn-On Time	1.0	μS
t _{stg}	Storage Time $I_{C} = 10A, I_{B1} = I_{B2} = 25mA; \\ R_{L} = 5 \Omega; V_{CC} \approx 50V$	5.0	μ S
tf	Fall Time	2.0	μS

NOTICE:

ISC reserves the rights to make changes of the content herein the datasheet at any time without notification. The information contained herein is presented only as a guide for the applications of our products.

ISC products are intended for usage in general electronic equipment. The products are not designed for use in equipment which require specialized quality and/or reliability, or in equipment which could have applications in hazardous environments, aerospace industry, or medical field. Please contact us if you intend our products to be used in these special applications.

ISC makes no warranty or guarantee regarding the suitability of its products for any particular purpose, nor does ISC assume any liability arising from the application or use of any products, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages.